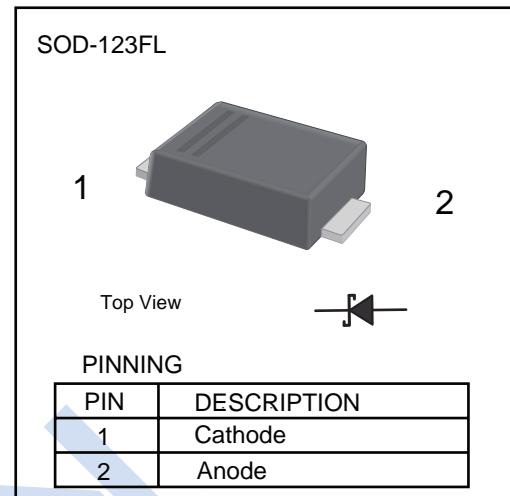


Schottky Diodes

1KK2102D-1KK2104D

■ Features

- Metal silicon junction, majority carrier conduction
- For surface mounted applications
- Low power loss, high efficiency
- High forward surge current capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications



■ Absolute Maximum Ratings and Electrical characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

Parameter	Symbols	1KK2102D	1KK2104D	Unit
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	20	40	V
Maximum RMS voltage	V_{RMS}	14	28	
Maximum DC Blocking Voltage	V_{DC}	20	40	
Maximum Instantaneous Forward Voltage at 1A	V_F		0.55	
Maximum Averaged Forward Rectified Current	$I_{F(AV)}$		1.0	A
Peak Forward Surge Current, 8.3 ms Single Half Sine Wave Superimposed on Rated Load	I_{FSM}		30	
Maximum DC Reverse Current $T_a=25^\circ\text{C}$ at rated DC blocking voltage $T_a=100^\circ\text{C}$	I_R	0.3 10		mA
Typical Junction Capacitance *1	C_j	110		pF
Typical Thermal Resistance *2	$R_{\theta JA}$	100		°C/W
Operating Junction Temperature Range	T_j	-55 ~ +125		°C
Storage Temperature Range	T_{stg}	-55 ~ +150		

* 1 Measured at 1MHz and applied reverse voltage of 4V D.C.

* 2 P.C.B. mounted with 2.0" x 2.0" (5x5 cm) copper pad areas.

■ Marking

NO.	1KK2102D	1KK2104D
Marking	DA	DB

Schottky Diodes

1KK2102D-1KK2104D

■ Typical Characteristics

Fig.1 Forward Current Derating Curve

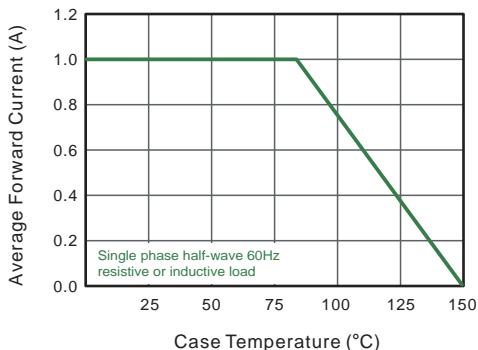


Fig.2 Typical Reverse Characteristics

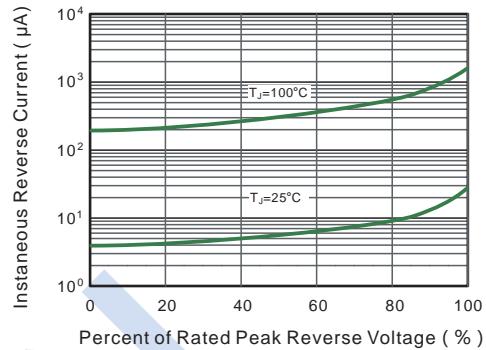


Fig.3 Typical Forward Characteristic

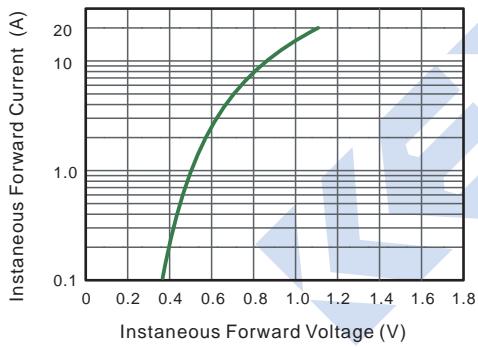


Fig.4 Typical Junction Capacitance

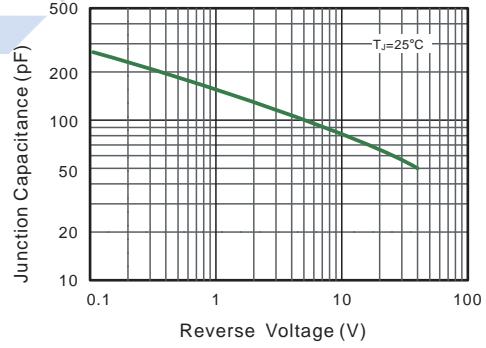


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current

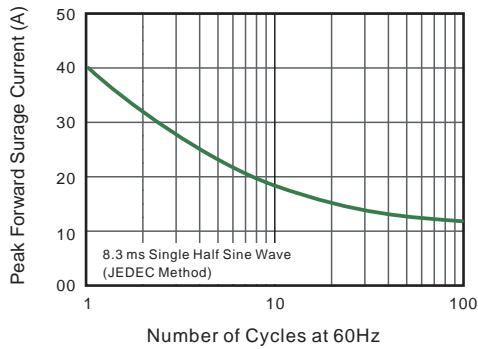
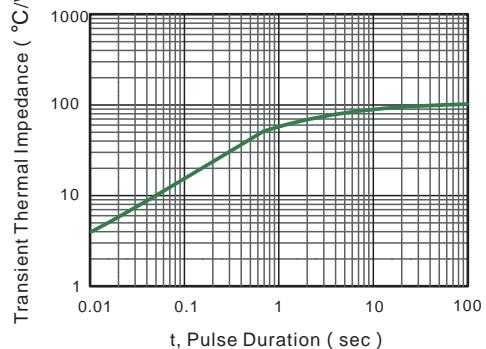


Fig.6- Typical Transient Thermal Impedance



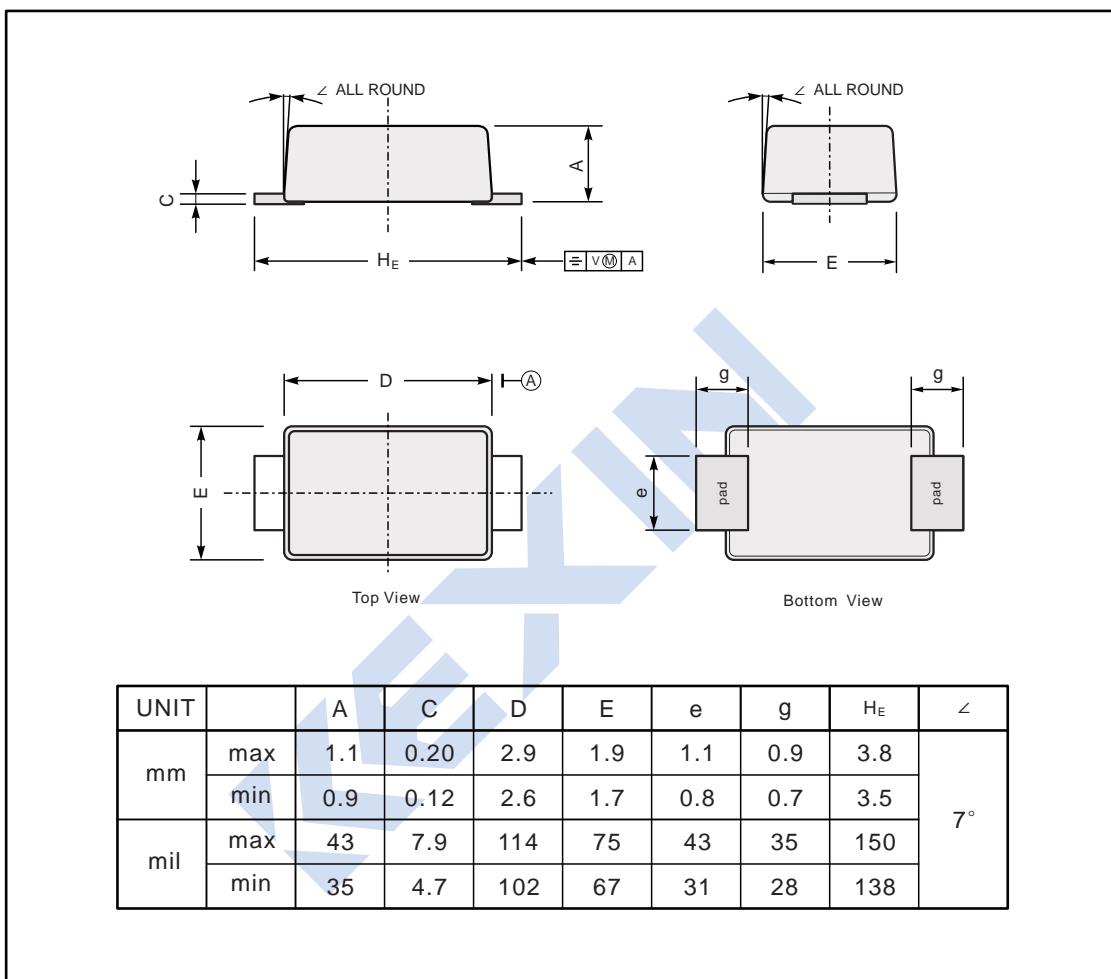
Schottky Diodes

1KK2102D-1KK2104D

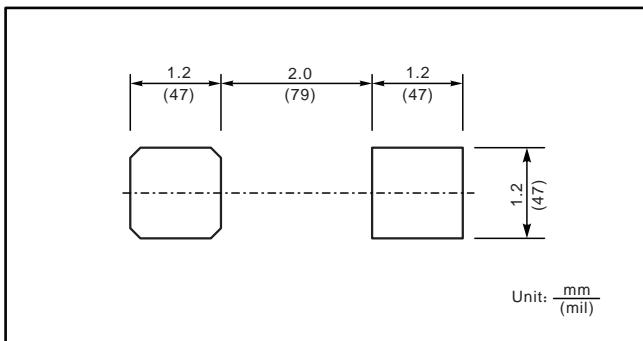
■ Package Outline Dimensions

Plastic surface mounted package; 2 leads

SOD-123FL



■ The Recommended Mounting Pad Size



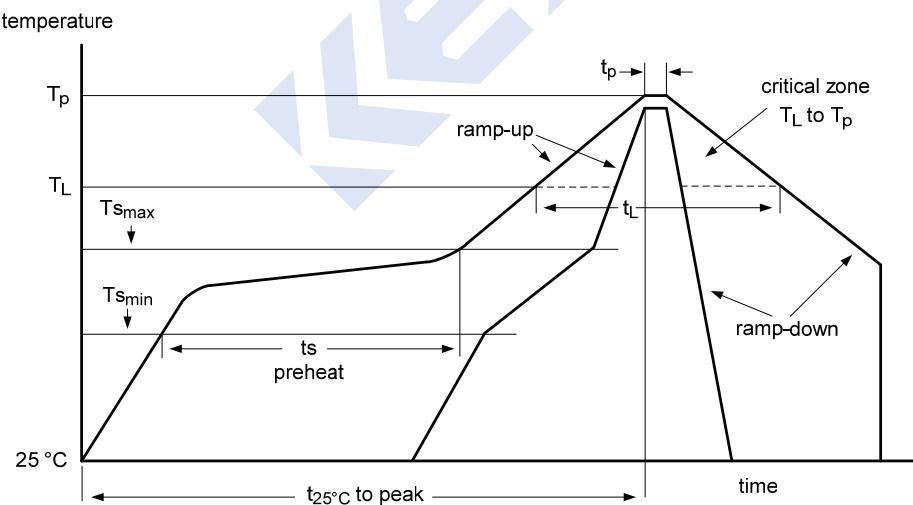
SMD Recommended Reflow Soldering Profile

Recommended Reflow Soldering Profile

The below temperature profile for moisture sensitivity characterization is based on the IPC/JEDEC joint industry standard: J-STD-020D-01.

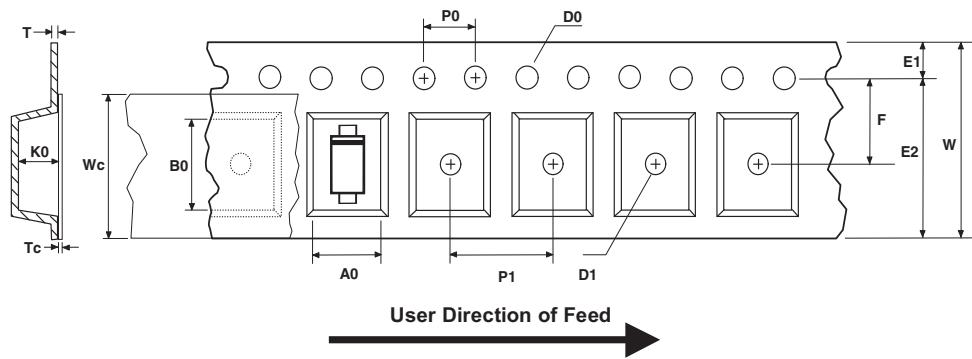
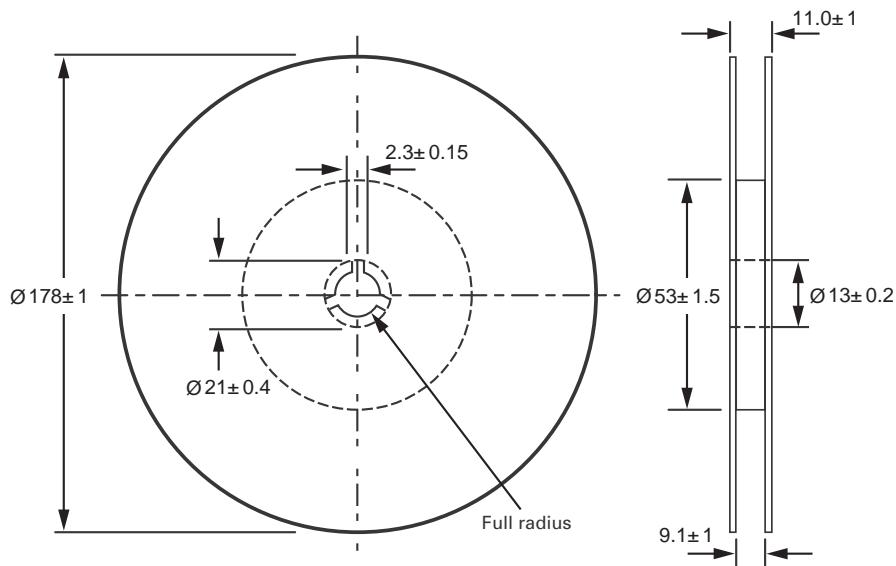
Profile Feature	SnPb eutectic assembly	Pb-free assembly
Average ramp-up rate ($T_{s\max}$ to T_p)	3 °C/s maximum	3 °C/s maximum
Preheat		
Temperature minimum ($T_{s\min}$)	100 °C	150 °C
Temperature maximum ($T_{s\max}$)	150 °C	200 °C
Time ($t_{s\min}$ to $t_{s\max}$)	60 s to 120 s	60 s to 180 s
Time maintained above		
Temperature (T_L)	183 °C	217 °C
Time (t_L)	60 s to 150 s	60 s to 150 s
Peak/classification temperature (T_p)	235 °C	260 °C
Number of allowed reflow cycles	3	3
Time within 5 °C of actual peak temperature (t_p)	10 s to 30 s	20 s to 40 s
Ramp-down rate	6 °C/s maximum	6 °C/s maximum
Time 25 °C to peak temperature	6 minutes maximum	8 minutes maximum

Reflow Soldering Profile



SOD-123FL封装料盘与带材尺寸图

Tape and reel data (Units: mm)



Dimensions are in millimeter														
Pkg type	A0	B0	W	D0	D1	E1	E2	F	P1	P0	K0	T	Wc	Tc
SOD-123FL (8mm)	1.95 +/-0.10	3.94 +/-0.10	8.00 +/-0.2	1.55 +/-0.05	1.00 +/-0.12	1.75 +/-0.10	6.25 min	3.50 +/-0.05	4.00 +/-0.1	4.00 +/-0.1	1.47 +/-0.10	0.20 +/-0.05	5.40 +/-0.02	0.02 +/-0.02

Shipping box



Inner Box: 182 mm × 182mm × 135mm
30,000 Pieces/Inner Box



Outer Box: 386mm × 386mm × 298mm
240,000 Pieces/Outer Box